DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

DOCKET NO. <u>CS03-028</u>

As a below named Inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled Shallow Low Energy Ion Implantation Into Pad Oxide For Improving Threshold Voltage Stability

he specification of which (check one)		•	
X is attached hereto.			
was filed on			
Application Serial No.			
and was amended on	if applicable)		ims, as
I hereby state that I have reviewed an amended by any amendment referred	d understand the contents of the about above.	ove Identified specification including the clai	with
I acknowledge the duty to disclose in	formation which is material to the e.	Xammation of this opposite	
I hereby claim foreign priority benefi inventor's certificate listed below and having a filing date before that of the	ts under Title 35, United States Coo	eign application for patent or inventor's certif	nt or ficate
Prior Foreign Application(s)		Priority Claimed:	
(Number)	(Country)	(Day/Month/Year Filed)	
	(Country)	(Day/Month/Year Filed)	
I hereby claim the benefit under Title as the subject matter of each of the manner provided by the first paragra information as defined in Title 37, Capplication and the national or PCT	e 35, United States Code §120 of ar claims of this application is not disclude the firm of Title 35, United States Code, Code of Federal Regulations, §1.56 international filing date of this appl	ny United States application(s) listed below a losed in the prior United States application in §112, I acknowledge the duty to disclose maa) which occurred between the filing date of lication:	nd, insofar the terial the prior
	(Filing Date) (Status)	(patented, pending, abandoned)	
I hereby declare that all statements belief are believed to be true; and futhe like so made are punishable by and that such willful false statement	made herein of my own knowledge arther that these statements were ma fine or imprisonment, or both, unde ts may jeopardize the validity of the	are true and that all statements made on inforded with the knowledge that willful false states Section 1001 of Title 18 of the United States application or any patent issued thereon.	mation and ments and es Code
POWER OF ATTORNEY: As a na	amed inventor, I hereby appoint the	following attorney(s) and/or agent(s) to prose to connected therewith. (list name & registrat	ecute this ion no.)
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